NSN 5962-01-050-9415

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View Online at https://aerobasegroup.com/nsn/5962-01-050-9415
Body Length:
Between 0.370 inches and 0.395 inches
Body Width:
Between 0.245 inches and 0.275 inches
Body Height:
Between 0.040 inches and 0.070 inches
Maximum Power Dissipation Rating:
400.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/buffered output and programmable and programmed and w/storage and
w/enable and w/disable and bipolar and w/open collector and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Precious Material And Location:
Terminals gold
Precious Material:
Gold
Test Data Document:
35351-151471 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Unit Of Measure:

16 flat leads

Shelf Life:

N/a

Terminal Type And Quantity:

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Demilitarization:

Yes - demil/mli

Fiig:

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